

DESCRIPTION

The SD07DFMC TVS diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebooks, and PDA's. It offers superior electrical characteristics such as low clamping voltage, low leakage current and high surge capability. It is designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lighting.

The SD07DFMC is in a SOD-123FL package and will protect one bidirectional line. It may be used to provide ESD protection up to $\pm 30\text{kV}$ (Contact and air discharge) according to IEC61000-4-2, and withstand peak pulse current up to 200A (8/20 μs) according to IEC61000-4-5.

Features

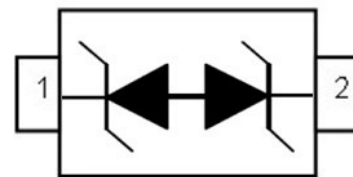
- ◆ Transient protection for high-speed data lines
- ◆ IEC61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact)
- ◆ Peak power dissipation: 3600W (8/20 μs)
- ◆ Working voltages : 7V
- ◆ Low clamping voltage
- ◆ Low leakage current
- ◆ Solid-state silicon-avalanche technology

Package Outline

Applications

- ◆ Power lines
- ◆ Personal digital assistants (PDA's)
- ◆ Microprocessors based equipment
- ◆ Notebooks, Desktops, and Servers
- ◆ Cell phone Handsets and Accessories
- ◆ Portable Electronics
- ◆ Peripherals

Circuit Diagram



- ◆ Packaging: Tape and Reel
- ◆ Quantity per reel: 3,000pcs
- ◆ Reel size: 7 inch

Absolute Maximum Rating (TA=25°C unless otherwise specified)

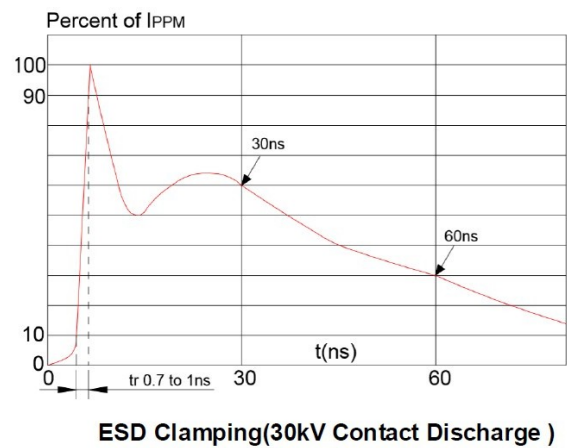
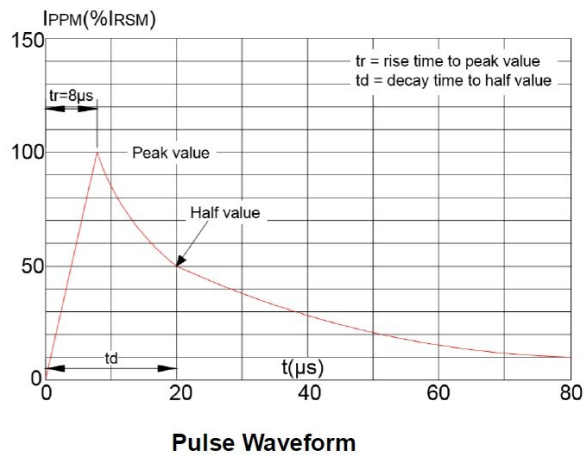
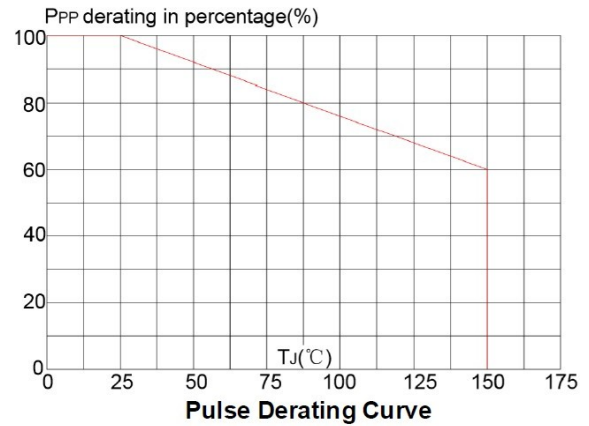
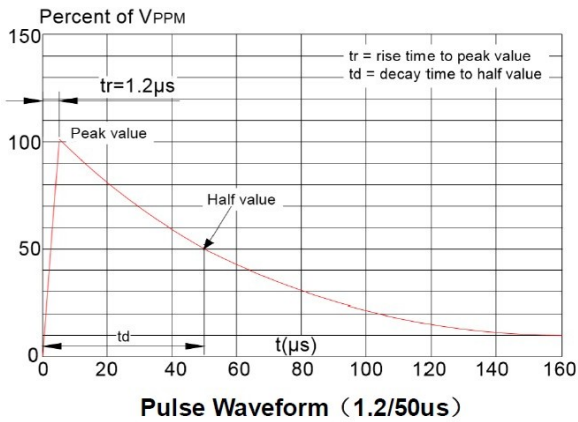
Parameter	Symbol	Value	Unit
ESD per IEC 61000-4-2 (Air)	VESD	± 30	KV
ESD per IEC 61000-4-2 (Contact)		± 30	
Peak Pulse Power(tp=8/20us waveform)	PPp	3600	W
Operating Temperature	TOPT	-55 to +125	°C
Storage Temperature	TSTG	-55 to +150	°C
Lead Solder Temperature – Maximum	TL	260(10 sec.)	°C

Electrical Characteristics (TA=25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
VRWM	Reverse Working Voltage				7	V
VBR	Reverse Breakdown Voltage	IT = 1mA	8		10	V
IR	Reverse Leakage Current	VRWM = 7V			1.0	μA
IPP	Peak Pulse Current	tp = 8/20μs			200	A
VC	Clamping Voltage	IPP = 200A, tp = 8/20μs			18	V
CJ	Junction Capacitance	VR = 0V, f = 1MHz		520	550	pF

The above data are for reference only.

ELECTRICAL CHARACTERISTICS CURVE



The curve above is for reference only.